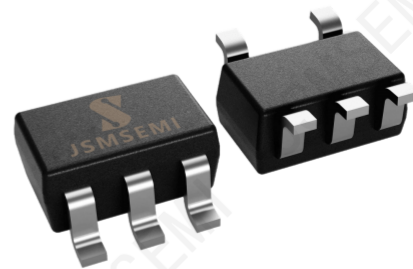


1、General Description

The 74LVC1G17 provides a buffer function with Schmitt trigger input. It is capable of transforming slowly changing input signals into sharply defined outputs.

The input can be driven from either 3.3V or 5V devices.

This feature allows the use of this device in a mixed 3.3V and 5V environment.



SOT-23-5

Features:

- Wide supply voltage range from 1.65V to 5.5V
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- CMOS low power consumption
- Direct interface with TTL levels
- Unlimited rise and fall times
- Input accepts voltages up to 5V
- Specified from -40°C to $+125^{\circ}\text{C}$
- Packaging information: SOT-23-5/SOT-353/XSON6

2、Block Diagram And Pin Description

2.1、Block Diagram



Figure 1. Logic symbol



Figure 2. IEC logic symbol

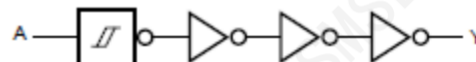
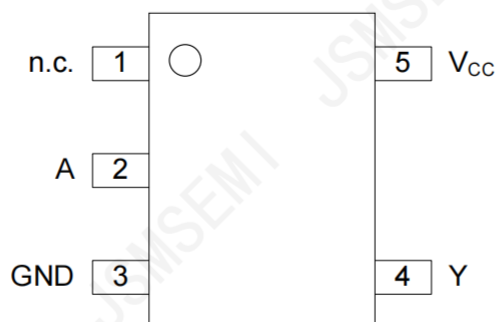


Figure 3. Logic diagram

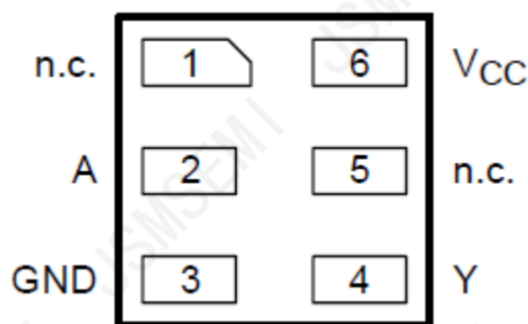
Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship, Quantity	Green
74LVC1G17GV,125-JSM	SOT-23-5	AFX	-40 to 125°C	3	T&R,3000	RoHS
74LVC1G17GW-JSM	SOT-353	AFX	-40 to 125°C	3	T&R,3000	RoHS

2.2、Pin Configurations



SOT23-5/SOT353



XSON6

2.3、Pin Description

Pin No. SOT23-5/SO T353	Pin No. XSON6	Pin Name	Description
1	1,5	n.c.	not connected
2	2	A	data input
3	3	GND	ground (0V)
4	4	Y	data output
5	6	Vcc	supply voltage

2.4、Function Table

Input	Output
A	Y
L	L
H	H

Note: H=HIGH voltage level; L=LOW voltage level.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input voltage	V_I	-	-0.5	+6.5	V
output voltage	V_O	Active mode	-0.5	$V_{CC}+0.5$	V
		Power-down mode; $V_{CC}=0V$	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
output clamping current	I_{OK}	$V_O > V_{CC}$ or $V_O < 0V$	-	± 50	mA
output current	I_O	$V_O=0V$ to V_{CC}	-	± 50	mA
supply current	I_{CC}	-	-	+100	mA
ground current	I_{GND}	-	-100	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	250	mW
soldering temperature	T_L	10s	260		°C

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+125	°C

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
HIGH-level output voltage	V_{OH}	$V_I = V_{T+}$ or V_{T-}	$I_O = -100\mu\text{A}; V_{CC} = 1.65\text{V to } 5.5\text{V}$	$V_{CC} - 0.1$	-	V
			$I_O = -4\text{mA}; V_{CC} = 1.65\text{V}$	1.2	-	V
			$I_O = -8\text{mA}; V_{CC} = 2.3\text{V}$	1.9	-	V
			$I_O = -12\text{mA}; V_{CC} = 2.7\text{V}$	2.2	-	V
			$I_O = -24\text{mA}; V_{CC} = 3.0\text{V}$	2.3	-	V
			$I_O = -32\text{mA}; V_{CC} = 4.5\text{V}$	3.8	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{T+}$ or V_{T-}	$I_O = 100\mu\text{A}; V_{CC} = 1.65\text{V to } 5.5\text{V}$	-	-	0.10 V
			$I_O = 4\text{mA}; V_{CC} = 1.65\text{V}$	-	-	0.45 V
			$I_O = 8\text{mA}; V_{CC} = 2.3\text{V}$	-	-	0.30 V
			$I_O = 12\text{mA}; V_{CC} = 2.7\text{V}$	-	-	0.40 V
			$I_O = 24\text{mA}; V_{CC} = 3.0\text{V}$	-	-	0.55 V
			$I_O = 32\text{mA}; V_{CC} = 4.5\text{V}$	-	-	0.55 V
input leakage current	I_I	$V_I = 5.5\text{V or GND}; V_{CC} = 0\text{V to } 5.5\text{V}$	-	-	± 1	μA
power-off leakage current	I_{OFF}	V_I or $V_O = 5.5\text{V}; V_{CC} = 0\text{V}$	-	-	± 2	μA
supply current	I_{CC}	$V_I = 5.5\text{V or GND}; I_O = 0\text{A}; V_{CC} = 1.65\text{V to } 5.5\text{V}$	-	-	4	μA
additional supply current	ΔI_{CC}	per pin; $V_I = V_{CC} - 0.6\text{V}; I_O = 0\text{A}; V_{CC} = 2.3\text{V to } 5.5\text{V}$	-	-	500	μA
input capacitance	C_I	-	-	5.0	-	pF

Note: All typical values are measured at maximum V_{CC} and $T_{amb} = 25^{\circ}\text{C}$.

3.3.2、DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
HIGH-level output voltage	V_{OH}	$V_I = V_{T+}$ or V_{T-}	$I_O = -100\mu\text{A}$; $V_{CC} = 1.65\text{V}$ to 5.5V	$V_{CC} - 0.1$	-	V
			$I_O = -4\text{mA}$; $V_{CC} = 1.65\text{V}$	0.95	-	V
			$I_O = -8\text{mA}$; $V_{CC} = 2.3\text{V}$	1.7	-	V
			$I_O = -12\text{mA}$; $V_{CC} = 2.7\text{V}$	1.9	-	V
			$I_O = -24\text{mA}$; $V_{CC} = 3.0\text{V}$	2.0	-	V
			$I_O = -32\text{mA}$; $V_{CC} = 4.5\text{V}$	3.4	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{T+}$ or V_{T-}	$I_O = 100\mu\text{A}$; $V_{CC} = 1.65\text{V}$ to 5.5V	-	-	0.10 V
			$I_O = 4\text{mA}$; $V_{CC} = 1.65\text{V}$	-	-	0.70 V
			$I_O = 8\text{mA}$; $V_{CC} = 2.3\text{V}$	-	-	0.45 V
			$I_O = 12\text{mA}$; $V_{CC} = 2.7\text{V}$	-	-	0.60 V
			$I_O = 24\text{mA}$; $V_{CC} = 3.0\text{V}$	-	-	0.80 V
			$I_O = 32\text{mA}$; $V_{CC} = 4.5\text{V}$	-	-	0.80 V
input leakage current	I_I	$V_I = 5.5\text{V}$ or GND; $V_{CC} = 0\text{V}$ to 5.5V	-	-	± 1	μA
power-off leakage current	I_{OFF}	V_I or $V_O = 5.5\text{V}$; $V_{CC} = 0\text{V}$	-	-	± 2	μA
supply current	I_{CC}	$V_I = 5.5\text{V}$ or GND; $I_O = 0\text{A}$; $V_{CC} = 1.65\text{V}$ to 5.5V	-	-	4	μA
additional supply current	ΔI_{CC}	per pin; $V_I = V_{CC} - 0.6\text{V}$; $I_O = 0\text{A}$; $V_{CC} = 2.3\text{V}$ to 5.5V	-	-	500	μA

3.3.3、AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ. ^[1]	Max.	Unit
A to Y propagation delay	t_{PLH}	see Figure 5	$V_{CC} = 1.65\text{V}$ to 1.95V	-	14	ns
			$V_{CC} = 2.3\text{V}$ to 2.7V	-	10	ns
			$V_{CC} = 2.7\text{V}$	-	9	ns
			$V_{CC} = 3.0\text{V}$ to 3.6V	-	8	ns
			$V_{CC} = 4.5\text{V}$ to 5.5V	-	7	ns
A to Y propagation delay	t_{PHL}	see Figure 5	$V_{CC} = 1.65\text{V}$ to 1.95V	-	12.5	ns
			$V_{CC} = 2.3\text{V}$ to 2.7V	-	11	ns
			$V_{CC} = 2.7\text{V}$	-	11	ns
			$V_{CC} = 3.0\text{V}$ to 3.6V	-	11	ns
			$V_{CC} = 4.5\text{V}$ to 5.5V	-	10	ns

Note:

[1] Typical values are measured at $T_{amb} = 25^{\circ}\text{C}$ and $V_{CC} = 1.8\text{V}$, 2.5V , 2.7V , 3.3V and 5.0V respectively.

3.3.4、AC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
A to Y propagation delay	t_{PLH}	see Figure 5	$V_{CC}=1.65V$ to $1.95V$	-	-	23	ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	17	ns
			$V_{CC}=2.7V$	-	-	15.5	ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	14	ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	12.5	ns
A to Y propagation delay	t_{PHL}	see Figure 5	$V_{CC}=1.65V$ to $1.95V$	-	-	20.8	ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	18.5	ns
			$V_{CC}=2.7V$	-	-	18.5	ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	18.5	ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	17	ns

3.3.5、Transfer Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
positive-going threshold voltage	V _{T+}	see Figure 6 and Figure 7	V _{CC} =1.8V	0.82	1.02	1.2	V
			V _{CC} =2.3V	1.03	1.25	1.45	V
			V _{CC} =3.0V	1.29	1.5	1.71	V
			V _{CC} =4.5V	1.84	2.15	2.41	V
			V _{CC} =5.5V	2.19	2.6	2.91	V
negative-going threshold voltage	V _{T-}	see Figure 6 and Figure 7	V _{CC} =1.8V	0.45	0.6	0.75	V
			V _{CC} =2.3V	0.64	0.8	0.96	V
			V _{CC} =3.0V	0.86	1.1	1.34	V
			V _{CC} =4.5V	1.35	1.75	2.09	V
			V _{CC} =5.5V	1.61	2.15	2.59	V
hysteresis voltage	V _H	see Figure 6 and Figure 7	V _{CC} =1.8V	-	0.4	-	V
			V _{CC} =2.3V	-	0.4	-	V
			V _{CC} =3.0V	-	0.42	-	V
			V _{CC} =4.5V	-	0.45	-	V
			V _{CC} =5.5V	-	0.47	-	V

3.3.6、Transfer Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
positive-going threshold voltage	V _{T+}	see Figure 6 and Figure 7	V _{CC} =1.8V	0.79	-	1.2	V
			V _{CC} =2.3V	1.00	-	1.45	V
			V _{CC} =3.0V	1.26	-	1.71	V
			V _{CC} =4.5V	1.81	-	2.41	V
			V _{CC} =5.5V	2.16	-	2.91	V
negative-going threshold voltage	V _{T-}	see Figure 6 and Figure 7	V _{CC} =1.8V	0.45	-	0.78	V
			V _{CC} =2.3V	0.64	-	0.99	V
			V _{CC} =3.0V	0.86	-	1.37	V
			V _{CC} =4.5V	1.35	-	2.12	V
			V _{CC} =5.5V	1.61	-	2.62	V
hysteresis voltage	V _H	see Figure 6 and Figure 7	V _{CC} =1.8V	-	0.4	-	V
			V _{CC} =2.3V	-	0.4	-	V
			V _{CC} =3.0V	-	0.42	-	V
			V _{CC} =4.5V	-	0.45	-	V
			V _{CC} =5.5V	-	0.47	-	V

4、Testing Circuit

4.1、AC Testing Circuit

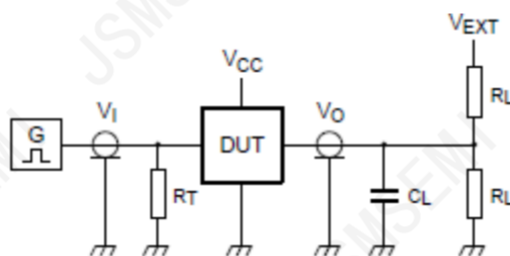


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

4.2、AC Testing Waveforms

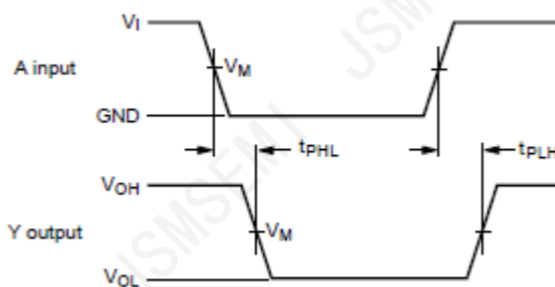


Figure 5. The data input (A) to output (Y) propagation delays

4.3、Transfer Characteristics Waveforms

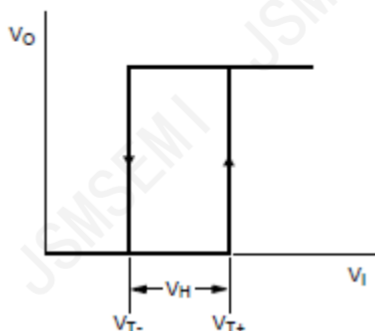


Figure 6. Transfer characteristic

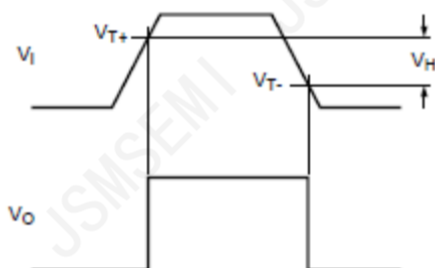


Figure 7. Definition of V_{T+} , V_{T-} and V_H

4.4、Measurement Points

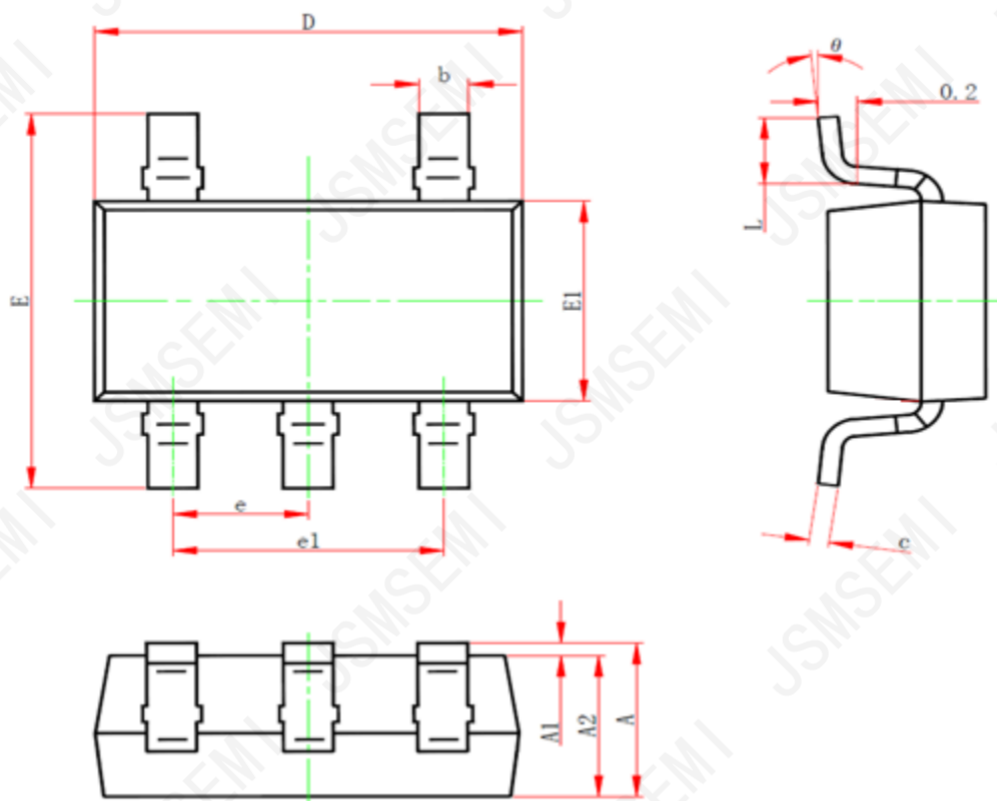
Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

4.5、Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65V to 1.95V	V_{CC}	$\leq 3ns$	30pF	1k Ω	open
2.3V to 2.7V	V_{CC}	$\leq 3ns$	30pF	500 Ω	open
2.7V	2.7V	$\leq 3ns$	50pF	500 Ω	open
3.0V to 3.6V	2.7V	$\leq 3ns$	50pF	500 Ω	open
4.5V to 5.5V	V_{CC}	$\leq 3ns$	50pF	500 Ω	open

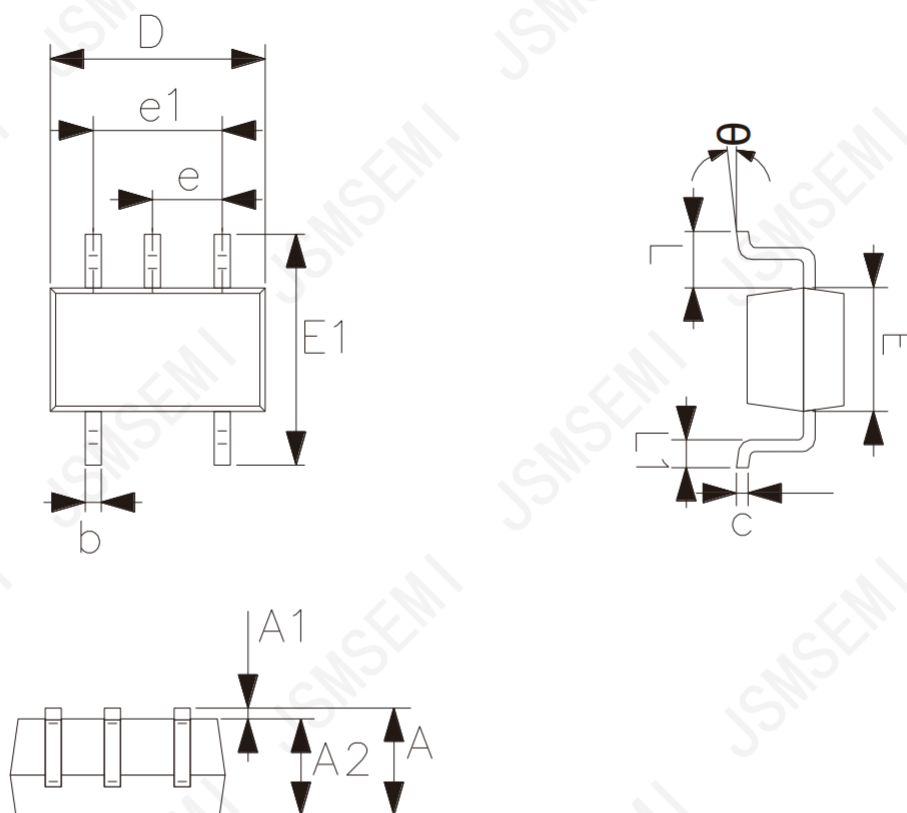
5、Package Information

5.1、SOT23-5



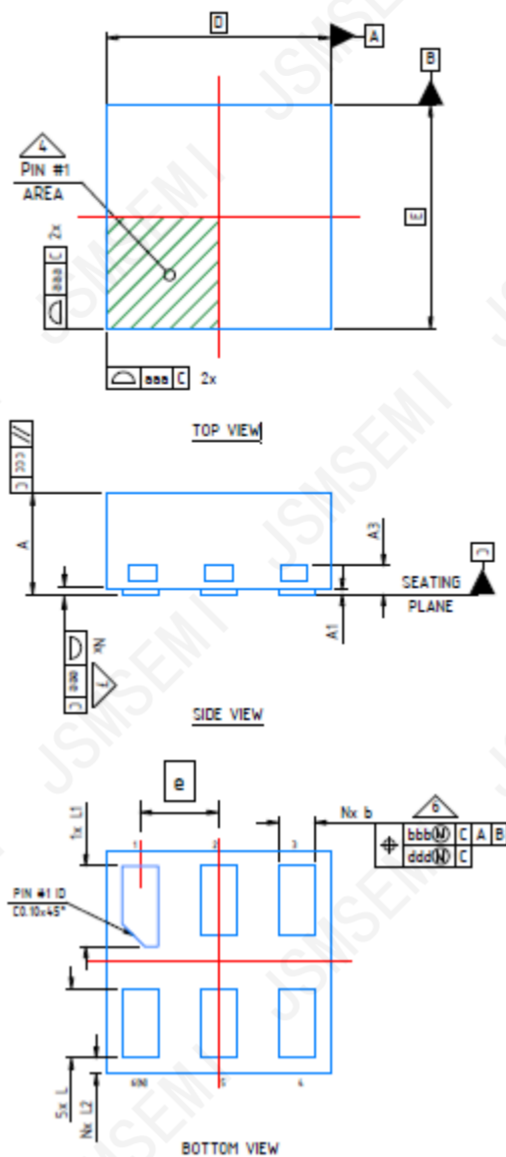
Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.26
A1	0.00	0.12
A2	1.00	1.20
b	0.30	0.50
c	0.10	0.20
D	2.82	3.02
E	2.60	3.00
E1	1.50	1.70
e	0.95	
e1	1.80	2.00
L	0.30	0.60
θ	0°	8°

5.2、SOT353



Symbol	Dimensions (mm)	
	Min.	Max.
A	0.90	1.10
A1	0.00	0.10
A2	0.90	1.00
b	0.15	0.35
c	0.11	0.175
D	2.00	2.20
E	1.15	1.35
E1	2.15	2.45
e	0.65	
e1	1.20	1.40
L	0.525	
L1	0.26	0.46
θ	0°	8°

5.3、XSON6(1*1*0.45-0.35)



Symbol	Dimensions (mm)	
	Min.	Max.
A	0.41	0.50
A1	0.00	0.05
A3	0.127	
b	0.11	0.21
D	1.00	
E	1.00	
e	0.35	
L	0.26	0.36
L1	0.31	0.41
L2	0.02	0.12

6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

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